

Analog Semiconductor IC

MRY1518E Series

12.5msec High speed detection, 1.5mT High sensitivity

CMOS MR Magnetic Sensor Switch

(IMPORTANT: Please check the last page for Genuine Product Labeling)

Rev. E13-01

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Products Data Sheet

Analog Semiconductor IC

12.5msec High speed detection, 1.5mT High sensitivity CMOS MR Magnet Sensor Switch

MRY1518E Series

GENERAL DESCRIPTIONS

MRY1518E series are monolithic ICs with built-in MR magnet resistive element and CMOS switch. It becomes the non-contact switch with low current consumption, high sensitivity and reliability which is combined with magnet.

A horizontal magnetic field parallel to the electrode of the package can be detected by an arbitrary polarity. (N pole \Leftrightarrow S pole)



FEATURES

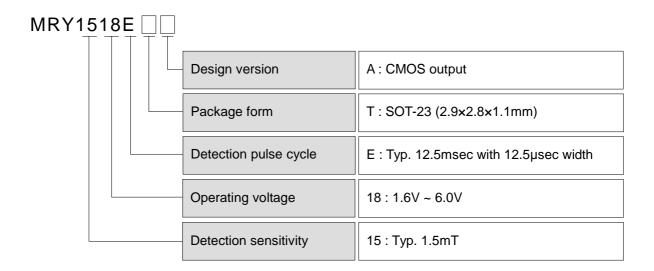
- CMOS + MR monolithic structure
- Low current consumption · · · · · 3.1µA (VIN=1.8V, Ta=25°C)
- High-sensitivity Typ. 1.5mT

- Detection pulse driving cycle Typ. 12.5msec with 12.5µsec width
- Magnetic direction Both direction / CMOS inverter one output
- Detection magnetic field Horizontal direction of marked side of package
 - (Electrode parallel both direction)
- Small package SOT-23 (2.9×2.8×1.1mm)

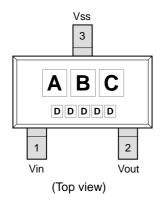
APPLICATIONS

- Detection of opening and closing: Mobile phone, Notebook PC, Microwave oven, Washing machine, Rice cooker, Refrigerator, Electronic dictionary, Digital camera, etc.
- Detection of position : Air cylinder, Antitheft window, Digital door lock, etc.
- Detection of water level : Water purifier, Humidifier, Bidet, etc.
- Detection of rotation : Water meter, Gas meter, Wattmeter, Speed meter, etc.
- Power supply switch: Cordless phone, Electric toothbrush, etc.

PRODUCTS NUMBERING GUIDE



PIN CONFIGURATION / MARKING SPECIFICATION



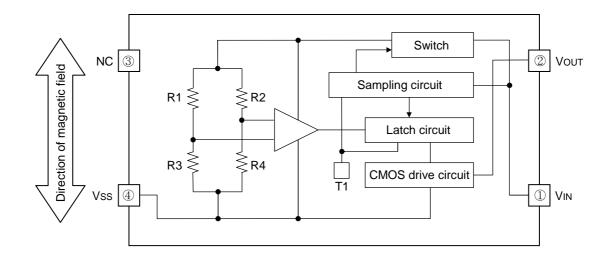
Pin Configuration

No.	Symbol	Descriptions
1	Vin	Voltage input
2	Vout	Output
3	Vss	Power ground

Marking Specification

Code	Mark	Contents	
Α	М	Series name	
ВС	EA	Products specification & version	
D	Internal rule	Lot number	

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Items	Symbol	Min.	Тур.	Max.	Conditions	Unit
Operating temperature	Topr	-40	-	+85		°C
Storage temperature	Tstg	-50	-	+125		°C
Supply voltage	VMAX	VIN-0.3	-	VIN+6.0		V
Assembly temp. condition	TASY	-	255	260	t=max:5sec/Tmax	°C

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, VDD=1.8V, Ta=25°C)

Items	Symbol	Min.	Тур.	Max.	Conditions	Unit
Operating voltage	VIN	1.6	1.8	6.0		V
Current consumption	IAVG	-	3.1	5.0		μΑ
Detection pulse driving cycle	ts	-	12.5	22.5	Pulse width: 1/1000	msec
"H"-level output voltage	Voн	0.9VIN	-	-	IOUT=+0.5mA	V
"L"-level output voltage	Vol	-	-	0.1VIN	IOUT=-0.5mA	V

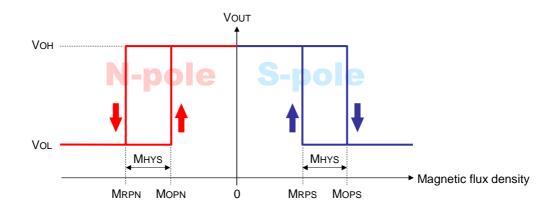
MAGNETIC CHARACTERISTICS

(Unless otherwise specified, VDD=1.8V, Ta=25°C)

Items	Symbol	Min.	Тур.	Max.	Unit	
Magnetic flux density at approxing point (H1.)	Mops	1.0*	1.5	2.2		
Magnetic flux density at operating point (H→L)	Mopn	-2.2	-1.5	-1.0 [*]	mT	
Magnetic flux density of release point (L. H)	MRPS	0.8	1.2	1.9*	mT	
Magnetic flux density at release point (L→H)	MRPN	-1.9 [*]	-1.2	-0.8	1111	
Width of hysteresis	MHYS	0.1*	0.3	0.8*	mT	

Note: The values with [*] marks are guaranteed by design, not tested in production.

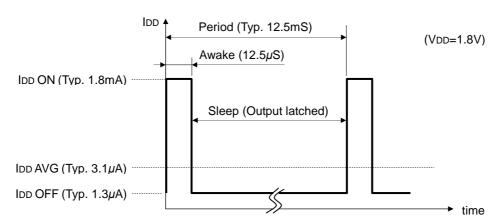
MAGNETIC-ELECTRIC CONVERSION CHARACTERISTIC



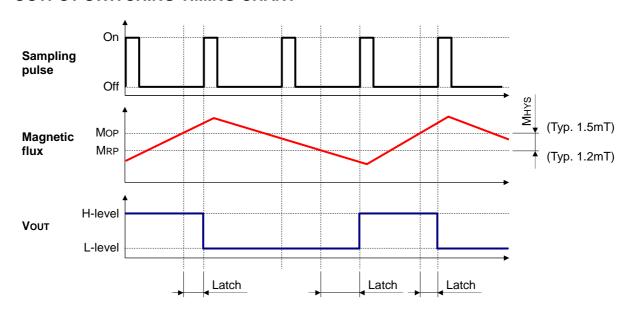
MAGNETIC FLUX DENSITY AND OUTPUT VOLTAGE LEVEL

Condition	Output lovel	
Magnet & Power	Output level	
Magnet = OFF / Power = ON	M = 0mT	High-level
Magnet = ON / Power = ON	M ≧ 2.2mT	Low-level
Magnet = OFF / Power = ON	M ≦ 0.8mT	High-level

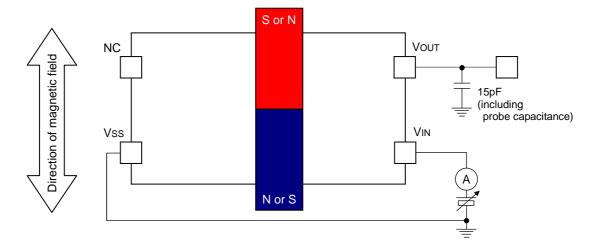
DETECTION PULSE DRIVING CYCLE (SAMPLING CYCLE)



OUTPUT SWITCHING TIMING CHART

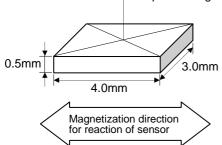


TEST CIRCUIT



STANDARD MAGNET SPECIFICATIONS

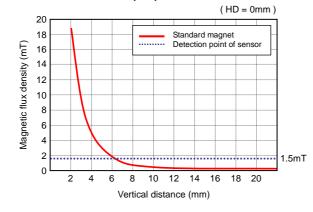
P-point : Magnetic flux density measuring position



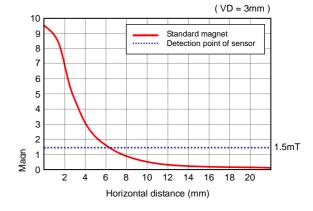
- Magnet maker : TDK Corp. / Japan
- Neodymium magnet
- Magnetic specification : NE047BW
- Size: 4.0 x 3.0 x 0.5mm

DETECTION DISTANCE SIMULATION (with standard magnet)

Vertical direction (VD)

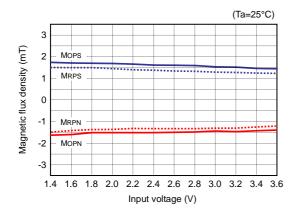


Horizontal direction (HD)

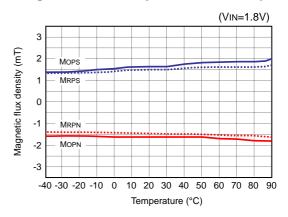


TYPICAL ELECTRIC CHARACTERISTICS

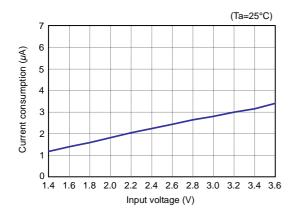
Magnetic flux density vs. Input voltage



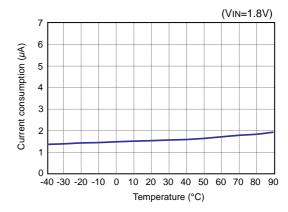
Magnetic flux density vs. Ambient temp.



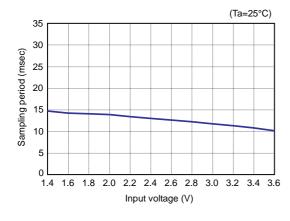
• Current consumption vs. Input voltage



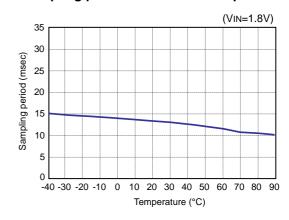
• Current consumption vs. Ambient temp.



• Sampling period vs. Input voltage



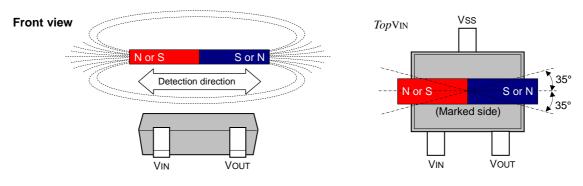
• Sampling period vs. Ambient temp.



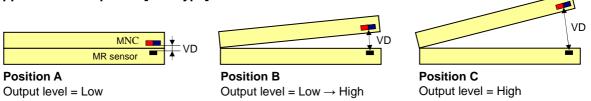
APPLICATION INFORMATIONS

• Detection of magnetic field

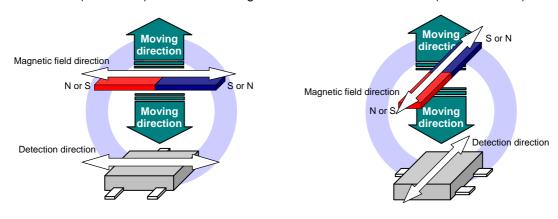
To operate output switch, the magnetic field should be applied to the sensor with sufficient magnetic flux density and correct direction. MR series are designed to be ON-state (L-level output) when the horizontal direction magnetic field is applied in parallel to the marked side of sensor, with sufficient magnetic flux (Mops or Mopn value) regardless of polarity of magnet. Because MR series detect the horizontal direction magnetic field, it has not influence of the reverse-magnetic field. And also, MR series detect the vertical direction magnetic field according to the level of magnetic flux, so that it is possible to apply to not only slide type but also fold type.



• Application example 1 -- [Fold type]

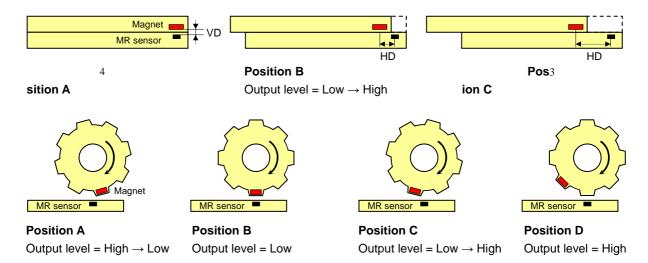


In case MR series is used for fold type cellular phone, IC sense the conditions of opening and shutting of the cover by detection of the magnetic flux according to the distance between IC and magnet. In position A, output is L-level (ON-state) because the detected magnetic flux is sufficient. The magnetic flux decrease according to the magnet is moved from IC (Position $A \rightarrow B$). Then the IC is turned H-level (OFF-state) because the magnetic flux become MRP or less (Position $B \rightarrow C$).



Rev. E13-01 MRY1518E Series

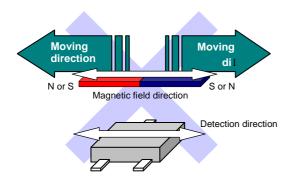
• Application example 2 -- [Slide type & Rotary type]



In the detection of the slide type, there are two ways of arrangement of magnetic field detecting direction against moving direction. One is parallel and another is cross with moving direction.

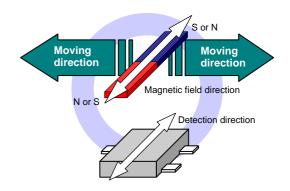
In case of parallel positioning of magnetic field with moving direction [arrangement 1], the output of IC might be L-level (ON-state) \rightarrow H-level (OFF-state) \rightarrow L-level (ON-state) \rightarrow H-level (OFF-state) due to reverse-magnetic field.

To prevent from this malfunction, it is recommended to arrange the detection direction of sensor and magnetic field to be crossed with moving direction of cover [arrangement 2].



[Arrangement 1]

Parallel the direction of detection magnetic field with the moving direction

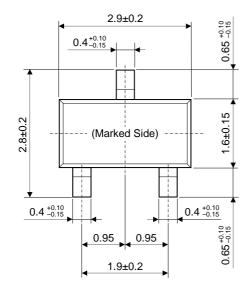


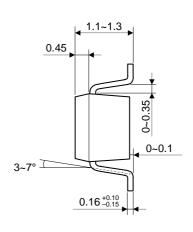
[Arrangement 2]

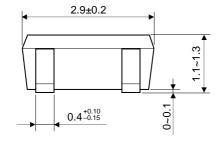
Cross the direction of detection magnetic field with the moving direction

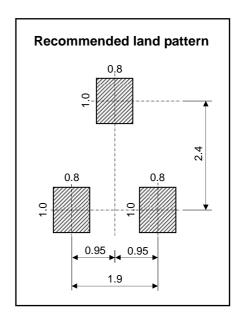
PACKAGE DIMENSIONS (SOT-23)

(Unit:mm)



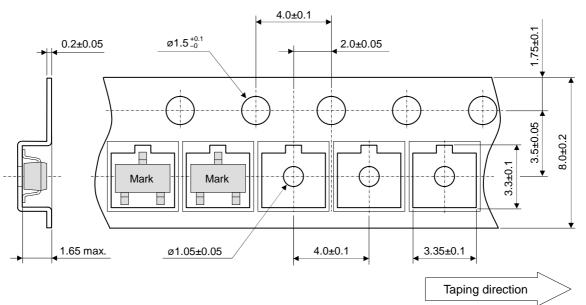






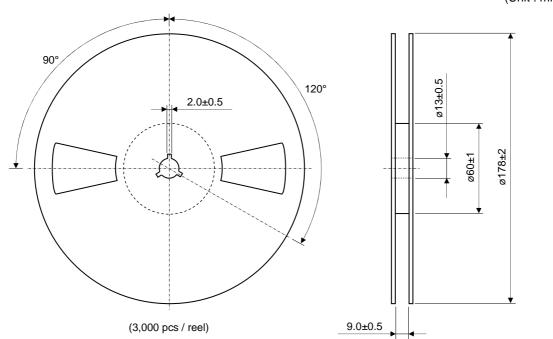
TAPING AND LOADING SPECIFICATIONS (SOT-23)

(Unit:mm)



REEL DIMENSIONS (SOT-23)

(Unit: mm)





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